

TRIPLE DIFFUSED PLANER TYPE HIGH VOLTAGE,HIGH SPEED SWITCHING

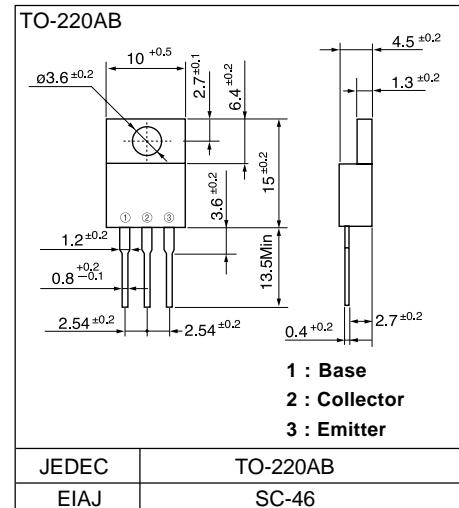
■ Features

- High voltage,High speed switching
- High reliability

■ Applications

- Switching regulators
- DC-DC convertor
- Solids state relay
- General purpose power amplifiers

■ Outline Drawings



■ Maximum ratings and characteristics

● Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	V _{CBO}	900	V
Collector-Emitter voltage	V _{CEO}	800	V
Collector-Emitter voltage	V _{CEO(SUS)}	-	V
Emitter-Base voltage	V _{EBO}	10	V
Collector current	I _C	3	A
Base current	I _B	1	A
Collector power dissipation	P _C	40	W
Operating junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-55 to +150	°C

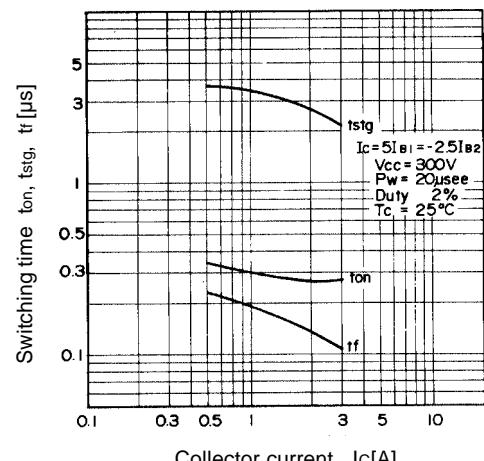
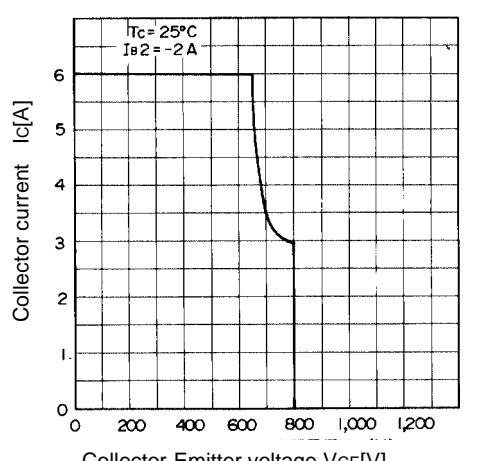
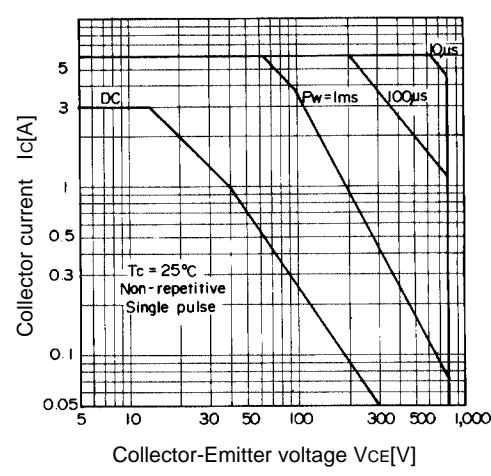
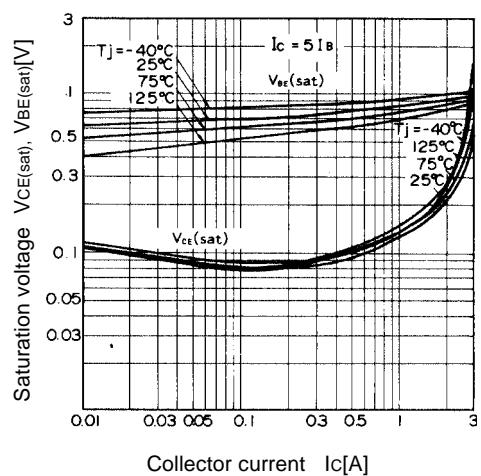
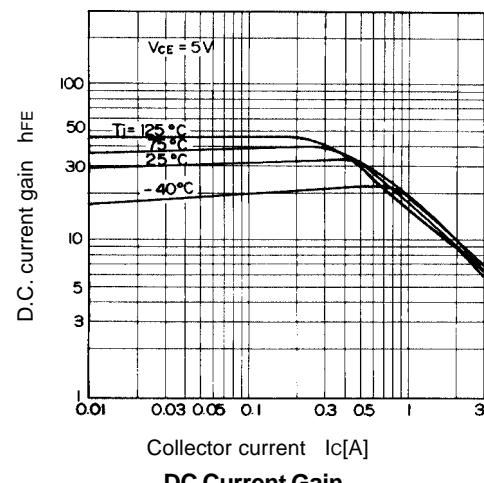
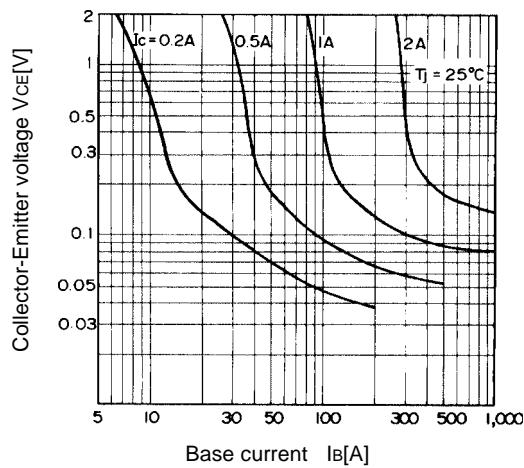
● Electrical characteristics (Tc =25°C unless otherwise specified)

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Base voltage	V _{CBO}	I _{CBO} = 1mA	900			V
Collector-Emitter voltage	V _{CEO}	I _{CEO} = 10mA	800			V
Collector-Emitter voltage	V _{CEO(SUS)}	I _C = A	-	-		V
Emitter-Base voltage	V _{EBO}	I _{EBO} = 1mA	10	-		V
Collector-Base leakage current	I _{CBO}	V _{CBO} = 900V		-	1.0	mA
Emitter-Base leakage current	I _{EBO}	V _{EBO} = 10V		-	1.0	mA
D.C. current gain	h _{FE}	I _C = 1A, V _{CE} = 5V	10			
Collector-Emitter saturation voltage	V _{CE(Sat)}	I _C = 1A, I _B = 200mA			1.0	V
Base-Emitter saturation voltage	V _{BE(Sat)}				1.5	V
*1	t _{on}	I _C = 2A, I _{B1} = 400mA			1.0	μs
Switching time	t _{stg}	I _{B2} = -800mA, R _L = 150 ohm			4.0	μs
	t _f	P _w = 20μs Duty=<2%			0.8	μs

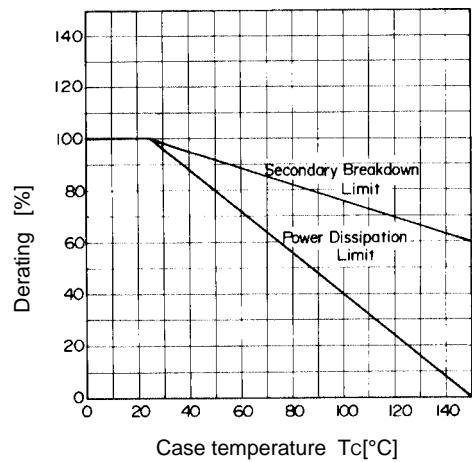
● Thermal characteristics

Item	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal resistance	R _{th(j-c)}	Junction to case			3.0	°C/W

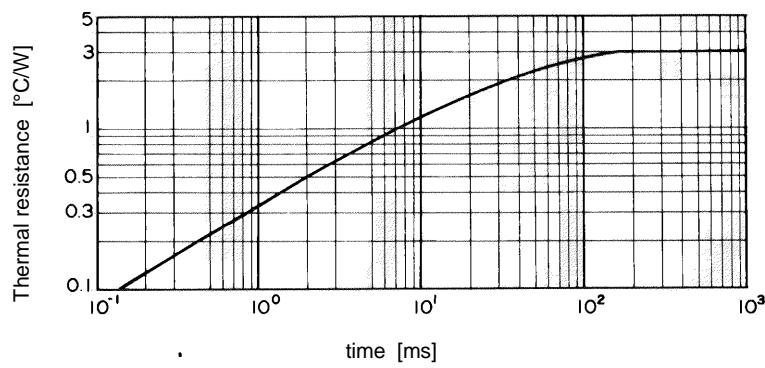
■ Characteristics



■ Characteristics



ASO Derating



Transient Thermal Resistance

*1 Switching Time Test Circuit

